Top-Down, Scalable Fabrication of High Purity Fluorescent Nanodiamonds

The MIT Faculty has made this article openly available. Please share how this access benefits you. Your story matters.

<table>
<thead>
<tr>
<th></th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td>As Published</td>
<td><a href="http://dx.doi.org/10.1364/CLEO_QELS.2013.QM2B.6">http://dx.doi.org/10.1364/CLEO_QELS.2013.QM2B.6</a></td>
</tr>
<tr>
<td>Publisher</td>
<td>Optical Society of America</td>
</tr>
<tr>
<td>Version</td>
<td>Final published version</td>
</tr>
<tr>
<td>Access</td>
<td>Tue Feb 05 23:15:29 EST 2019</td>
</tr>
<tr>
<td>Citable Link</td>
<td><a href="http://hdl.handle.net/1721.1/86154">http://hdl.handle.net/1721.1/86154</a></td>
</tr>
<tr>
<td>Terms of Use</td>
<td>Article is made available in accordance with the publisher's policy and may be subject to US copyright law. Please refer to the publisher's site for terms of use.</td>
</tr>
<tr>
<td>Detailed Terms</td>
<td></td>
</tr>
</tbody>
</table>
Top-Down, Scalable Fabrication of High Purity
 Fluorescent Nanodiamonds

Matthew E. Trusheim1, Luozhou Li2, Ophir Gaathon3, Edward H. Chen1 and Dirk R. Englund1

1Dept. of Electrical Engineering and Computer Science, Massachusetts Institute of Technology
Building 36-569; Cambridge, MA 02139, USA

2Department of Electrical Engineering, Columbia University, New York, NY, 10027, USA

3Department of Applied Physics and Applied Mathematics, Columbia University, New York, NY, 10027, USA

mtrush@mit.edu

Abstract: We demonstrate a fabrication technique for high volume production of high-quality nanocrystals from bulk chemical vapor deposition diamond. Ramsey and Spin-Echo measurements confirm the long spin coherence of nitrogen vacancy centers in these nanocrystals.

© 2013 Optical Society of America

OCIS codes: 220.4241 Nanostructure fabrication, 270.5585 Quantum information and processing, 280.1415 Biological sensing and sensors

The spin properties of the negatively charged nitrogen vacancy center (NV) in diamond have made it the focus of many recent investigations across a broad range of fields [1]. Prominent among these are works in quantum-enabled sensing, where the NV is used as a local magnetic [2] and electric [3] field sensor. In addition, there is interest in using NV-containing nanocrystalline diamond as a biological labeling agent due to its cytocompatibility, fluorescent brightness and suitability for super-resolution imaging [4, 5]. Combining imaging studies with high-performance sensing requires high purity nanocrystals with good spin properties. However, commercially available detonation and high-pressure high-temperature diamond nanocrystals are of lower quality than the bulk chemical vapor deposition (CVD) diamond used in the sensing proof-of-concept experiments, substantially diminishing the phase coherence time of the NV center and therefore its suitability for quantum information and sensing applications [6]. Here, we demonstrate a method by which we produce a high yield of NV-containing CVD diamond nanocrystals, allowing for a substantial increase in NV phase coherence time and enabling the use of diamond nanocrystals as high-sensitivity field sensors and long-coherence spin qubits.

Fabricating nanocrystals directly from bulk diamond presents several challenges. Traditional electron beam lithography and oxygen reactive ion etching (RIE), which has been used extensively to create diamond nanostructures, struggles to reach resolutions of lower than 50 nm with the smallest structures demonstrated in diamond having dimensions of 75 nm [7]. In addition, fabricating large quantities of such structures at high resolution across a macro-scale diamond substrate would be extremely time-consuming. We resolve these issues by using a self-aligned masking process, in which nanoscale metallic grains serve as an etch mask. The metallic grains can be extremely small and deposited with high density across a large surface in parallel, for example via sputtering. Ordinarily, the small size of these seeds would limit the aspect ratio and ultimate size of the resulting structures. However, due to the anisotropic nature of the plasma in the oxygen RIE that we perform, we achieve a final size and aspect ratio that is suitable to host NV centers for use as sensors.

After fabrication, we induced NV center formation through ion implantation and annealing, and mechanically separated the diamond nanocrystals from the bulk. We then proceeded with optical measurements using confocal microscopy and pulsed optically detected magnetic resonance (ODMR) to determine the spin properties of the CVD nanodiamonds. After identifying single NV centers through confocal scans, fluorescent spectra and second order autocorrelation, we measured the characteristic coherence times of the system, T2∗ and T2, via Ramsey and Hahn Echo ODMR sequences, respectively. The resulting values are T2∗ = 497 ns, and T2 = 840 ns.

These phase coherence times could be improved by the use of advanced dynamic decoupling techniques, including Carr-Purcell-Meiboom-Gill sequences, which have been demonstrated to provide an increase of a factor of two over spin echo in nanodiamond systems [6] and an order of magnitude in C13 nuclear-spin limited systems [8]. In addition, a reduction in nitrogen implant dose would further lower the number of paramagnetic impurities and boost coherence time. The NV density would be lowered as a consequence, but this could be counteracted by increasing implantation
Fig. 1. (a) Scanning electron micrograph of CVD diamond nanocrystals attached to bulk diamond substrate. (b) Confocal fluorescence scan of detached CVD nanocrystals on a glass substrate. The red box indicates a nanocrystal containing a single quantum emitter as determined by the second order autocorrelation function. (c) Fluorescent spectrum of a detached nanocrystal, confirming the presence of NV with the characteristic zero-phonon line at 638 nm. (d) Ramsey measurement on a single NV showing spin phase coherence time $T_2^* = 497$ ns.

yield, for example through use of a C$^{12}$ co-implant [9]. Even without these optimizations, our spin system sets a record $T_2^*$ time for diamond nanocrystals, which underscores the viability of this method for creation of long-coherence NV systems. When combined with the ease of mass parallel fabrication, these CVD diamond nanocrystals can enable a multitude of sensing and quantum information procedures at the nanoscale.

References